

2N4856, 2N4857, 2N4858, 2N4859, 2N4860, 2N4861

N-Channel Silicon Junction Field-Effect Transistor

- Choppers
- Commutators
- Analog Switches

Absolute maximum ratings at $T_A = 25^\circ\text{C}$

	2N4856, 2N4857, 2N4858	2N4859, 2N4860, 2N4861
Reverse Gate Source Voltage	- 40 V	- 30 V
Reverse Gate Drain Voltage	- 40 V	- 30 V
Continuous Device Dissipation	1.8 W	1.8 W
Power Derating	10 mW/°C	10 mW/°C
Continuous Forward Gate Current	50 mA	50 mA

At 25°C free air temperature:

Static Electrical Characteristics

		2N4856 2N4859		2N4857 2N4860		2N4858 2N4861		Process NJ132	
		Min	Max	Min	Max	Min	Max	Unit	Test Conditions
Gate Source Breakdown Voltage 2N4856, 2N4857, 2N4858 2N4859, 2N4860, 2N4861	$V_{(BR)GSS}$		- 40		- 40		- 40	V	$I_G = - 1\mu\text{A}, V_{DS} = \emptyset\text{V}$
			- 30		- 30		- 30	V	$I_G = - 1\mu\text{A}, V_{DS} = \emptyset\text{V}$
Gate Reverse Current 2N4856, 2N4857, 2N4858	I_{GSS}		- 250		- 250		- 250	pA	$V_{GS} = - 20\text{V}, V_{DS} = \emptyset\text{V}$
			- 500		- 500		- 500	nA	$V_{GS} = - 20\text{V}, V_{DS} = \emptyset\text{V}$ $T_A = 150^\circ\text{C}$
Gate Reverse Current 2N4859, 2N4860, 2N4861	I_{GSS}		- 250		- 250		- 250	pA	$V_{GS} = - 15\text{V}, V_{DS} = \emptyset\text{V}$
			- 500		- 500		- 500	nA	$V_{GS} = - 15\text{V}, V_{DS} = \emptyset\text{V}$ $T_A = 150^\circ\text{C}$
Gate Source Cutoff Voltage	$V_{GS(OFF)}$	- 4	- 10	- 2	- 6	- 0.8	- 4	V	$V_{DS} = 15\text{V}, I_D = 0.5\text{ nA}$
Drain Saturation Current (Pulsed)	I_{DSS}	50		20	100	8	80	mA	$V_{DS} = 15\text{V}, V_{GS} = \emptyset\text{V}$
Drain Cutoff Current	$I_{D(OFF)}$		250		250		250	pA	$V_{DS} = 15\text{V}, V_{GS} = - 10\text{V}$
			500		500		500	nA	$V_{DS} = 15\text{V}, V_{GS} = - 10\text{V}$ $T_A = 150^\circ\text{C}$
Drain Source ON Voltage	$V_{DS(ON)}$		0.75 (20)		0.5 (10)		0.5 (5)	V (mA)	$V_{GS} = \emptyset\text{V}, I_D = ()$

Dynamic Electrical Characteristics

Common Source ON Resistance	$r_{ds(on)}$		25		40		60	Ω	$V_{GS} = \emptyset\text{V}, I_D = \emptyset\text{A}$	$f = 1\text{ kHz}$
Common Source Input Capacitance	C_{iss}		18		18		18	pF	$V_{DS} = \emptyset\text{V}, V_{GS} = - 10\text{V}$	$f = 1\text{ MHz}$
Common Source Reverse Transfer Capacitance	C_{rss}		8		8		8	pF	$V_{DS} = \emptyset\text{V}, V_{GS} = - 10\text{V}$	$f = 1\text{ MHz}$

Switching Characteristics

Turn ON Delay Time	$t_{d(on)}$		6 (20) [-10]		6 (10) [- 6]		10 (5) [- 4]	ns (mA) [V]	$V_{DD} = 10\text{V}, V_{GS} = \emptyset\text{V}$ $I_{D(ON)} = ()$ $V_{GS(OFF)} = []$ (2N4856, 2N4859) $R_L = 465\Omega$ (2N4857, 2N4860) $R_L = 953\Omega$ (2N4858, 2N4861) $R_L = 1910\Omega$
Rise Time	t_r		3 (20) [-10]		4 (10) [- 6]		10 (5) [- 4]	ns (mA) [V]	
Turn OFF Delay Time	$t_{d(off)}$		25 (20) [-10]		50 (10) [- 6]		100 (5) [- 4]	ns (mA) [V]	

TO-18 Package

See Section G for Outline Dimensions

Pin Configuration

1 Source, 2 Drain, 3 Gate & Case

Surface Mount

SMP4856, SMP4857, SMP4858,
SMP4859, SMP4860, SMP4861

